

SILICON RECTIFIER

VOLTAGE RANGE 50 to 1000 Volts CURRENT 1.0 Ampere

FEATURES

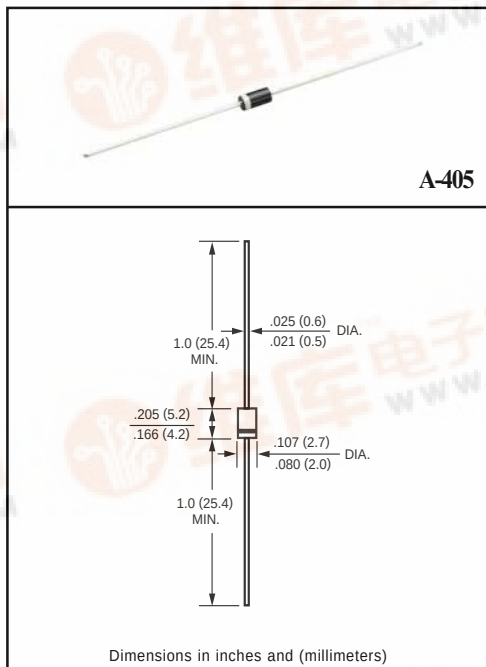
- * High reliability
- * Low leakage
- * Low forward voltage drop
- * High current capability

MECHANICAL DATA

- * Case: Molded plastic
- * Epoxy: Device has UL flammability classification 94V-O
- * Lead: MIL-STD-202E method 208C guaranteed
- * Mounting position: Any
- * Weight: 0.20 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
 Single phase, half wave, 60 Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.



MAXIMUM RATINGS (At Ta = 25°C unless otherwise noted)

RATINGS	SYMBOL	RL1N4001	RL1N4002	RL1N4003	RL1N4004	RL1N4005	RL1N4006	RL1N4007	UNITS
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at Ta = 55°C	Io	1.0							Amps
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	IFSM	30							Amps
Typical Junction Capacitance (Note)	Cj	15							pF
Typical Thermal Resistance	RθJA	50							°C/W
Operating and Storage Temperature Range	Tj, TSTG	-65 to + 175							°C

ELECTRICAL CHARACTERISTICS (At Ta = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	RL1N4001	RL1N4002	RL1N4003	RL1N4004	RL1N4005	RL1N4006	RL1N4007	UNITS
Maximum Instantaneous Forward Voltage at 1.0A DC	VF	1.1							Volts
Maximum DC Reverse Current @ Ta = 25°C	IR	5.0							uAmps
Maximum DC Blocking Voltage @ Ta = 100°C		50							uAmps
Maximum Full Load Reverse Current Average, Full Cycle (375 (9.5mm) lead length at TL = 75°C		30							uAmps

NOTES: * Measured at 1 MHz and applied reverse voltage of 4.0 volts

RATING AND CHARACTERISTIC CURVES (RL1N4001 THRU RL1N4007)

